SUPERCONDUCTING NANOTECHNOLOGY

I.TECHNICAL SPECIFICATION OF TERAHERTZ DETECTION SYSTEMS

Product description:

The Terahertz detection systems are optimized for three frequency ranges, which cover the overall range of 0.3-70 THz. The system incorporates a MoRe/NbN Superconducting Hot-Electron Bolometer (SHEB) mounted on a silicon/germanium lens and low-noise cryogenically cooled high electron mobility field-effect transistors (HEMT) amplifier.

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Scontel offers the fastest Terahertz receivers, which have a sensitivity comparable with the best detection systems available today.

Technical specifications:

Type 1, 1a: Hybrid antenna (Ø12 mm silicon hyperhemispherical lens and logarithmic periodic spiral antenna)

Туре		1	1a	
Frequency range, THz		0.3-3		
Upper level of dyna (3dB compres	amic range, μW sion point)	0.1		
Noise equivalent power (NEP), W·Hz ^{-1/2}		5-7x10 ⁻¹⁴	3-5x10 ⁻¹³	
Responsivity, V/W (own HEB characteristic)		~10,000	~ 3,000	
Response time, ns		1	0.05	
Sensitive material		MoRe	NbN	
Bandwidth of HEMT amplifier, MHz		0.01-200	1-3500	
Maximum power handling capacity		50 μW		
Input beam	Max diameter	10 mm		
	Beam pattern	F/3 to F/∞ (collimated beam)		



Type 2, 2a: Silicon lens (Ø12mm or Ø4mm silicon hyperhemispherical lens)	Type 2, 2a:	Silicon lens (Ø12mm	ı or Ø4mm silicon	hyperhemispherical lens)
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Туре		2	2a
Frequency range, THz		1-12 (40)	
Upper level of dyna (3dB compres	amic range, μW sion point)	50	
Noise equivalent power (NEP), W·Hz ^{-1/2}		1-2x10 ⁻¹¹	6-8x10 ⁻¹¹
Responsivity, V/W (own HEB characteristic)		~ 300	~ 100
Response time, ns		1	0.1
Sensitive material		MoRe	NbN
Bandwidth of HEMT amplifier, MHz		0.01-200	1-3500
Maximum power handling capacity		10 mW	
Input beam	Max diameter	10 mm (3 mm)	
	Beam pattern	F/3 to F/∞ (collimated beam)	

Type 3, 3a: Germanium lens (Ø12 mm germanium hyperhemispherical lens)

Туре		3	3a
Frequency range, THz		25-70	
Upper level of dyna (3dB compres	amic range, μW sion point)	2	
Noise equivalent power (NEP), W·Hz ^{-1/2}		1-2x10 ⁻¹²	4-5x10 ⁻¹²
Responsivity, V/W (own HEB characteristic)		~ 2,000	~ 500
Response time, ns		1	0.1
Sensitive material		MoRe	NbN
Bandwidth of HEMT amplifier, MHz		0.01-200	1-3500
Maximum power handling capacity		1 mW	
Input beam	Max diameter	10 mm	
	Beam pattern	F/3 to F/∞ (collimated beam)	



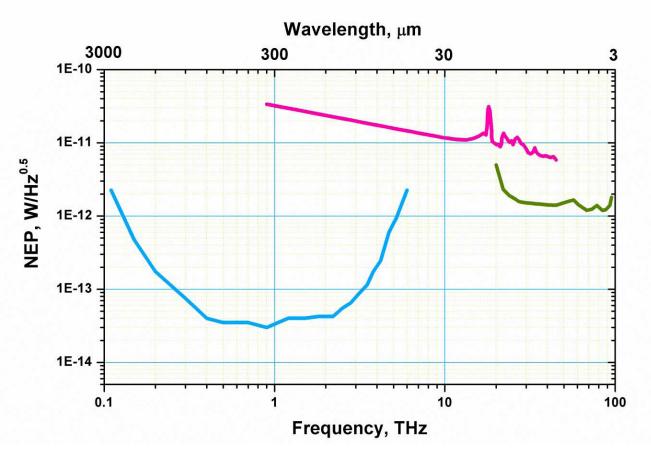
General parameters:

Number of channels: **1 or 2** Electrical connection: **SMA-50 Ohm** Driver interface: USB, LabVIEW

Advantages of the System:

Response time down to **50 ps** Possibilities for different beam geometry [beam pattern **F/3** to **F/∞** (collimated beam)] Registration of short pulses(THz pulses from **nano-** to **pico**seconds) Ultra-high sensitivity

Typical frequency dependence of the noise equivalent power (NEP) for three types of detecting system:



Blue line - type 1; Red line - type 2; Green line - type 3



II. CHARACTERISTICS of the COOLING SYSTEMS

Two types of cooling system are available:

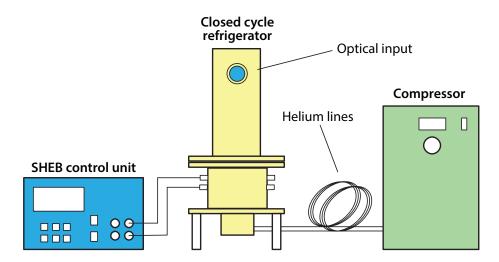
1) Liquid helium Cryostat



2) Closed-Cycle Refrigerator (Cryogenic-Free)

Element/Parameter	Closed-cycle refrigerator	Compressor	Control unit
Weight, kg	25	75	1
Length x width x height	240 x 240 x 580 mm	450 x 320 x 560 mm	240 x 260 x 140 mm
Preparation time	150 min	-	-
Maintenance, hours	10,000	30,000	-
Power consumption	1.5	kW*	30 W*

*Voltage of control unit and compressor: 100-240 V/ 50-60 Hz (can be adapted to any other standard networks)





III. CONFIGURATION OF THE TERAHERTZ DETECTION SYSTEMS

TYPE OF SYSTEM	THE COMPLETE SYSTEM
	1. Detection Unit Based on: Liquid helium cryostat (Capacity – 1 liter (2 liters)) LHe bath hold time – ≥5 hours (≥7 hours) or Closed cycle refrigeration (time to reach operating temperature<2.5 hours)
	THz window IR radiation filter Cupronickel or Stainless steel coaxial cable
	Bolometer holder: SHEB Bolometet chip Micro-strip line with SMA connector Hypersemispherical lens (HRFZ Si or Ge) Heater
ALL TYPES	Cryogenically cooled HEMT preamplifier Gain – >27 dB (with Bias-T adapter) Optimal frequency range: 0.1 – 250 MHz 1 ns version 1 – 3500 MHz 50 ps version
	2. Control Unit Input voltage AC: 200-240 V, 50-60 Hz
	Output for HEMT amplifier: DC +/-6 V, 50 mA Output for Heater: DC 0-5 V, accuracy +/-1 mV Output for bolometer: It can be used in two modes - constant current and constant voltage Room temperature amplifier (<u>optionally</u>): 0.1 – 250 MHz 1 – 3500 MHz
	3. Compressor
	4. Operation manual



IV. DELIVERY TERMS OF TERAHETZ DETECTION SYSTEMS

Delivery Time:

Type 1, 1a: 12-14 weeks after receipt of Purchase Order;

Type 2, 2a: 12-14 weeks after receipt of Purchase Order.

Type 3, 3a: 13-15 weeks after receipt of Purchase Order.

Delivery Terms: DAP Buyer's city (Incoterms 2010) Payment Terms: Payment only after 30 days of successful testing.

All bank charges are at the Seller's cost